



Jiangsu Yangjie Runau Semiconductor Co.,Ltd

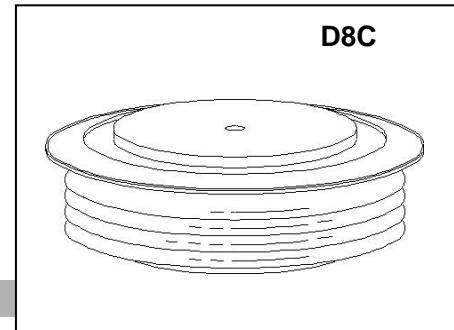
YA796-POWER THYRISTOR

1500-2500V<sub>DRM</sub>

## SOFT FAST RECOVERY DIODE

### Features:

- . All diffused structure
- . High surge rating
- . Blocking capability up to 2500 volts
- . Soft reverse recovery
- . Rugged ceramic hermetic package
- . Pressure assembled device



## ELECTRICAL CHARACTERISTICS AND RATINGS

### Reverse Blocking

Device Type	$V_{RRM}$ (1)	$V_{RSM}$ (1)
YA796PE	1500	1700
YA796PN	1800	2000
YA796L	2000	2000
YA796LB	2200	2400
YA796LE	2500	2700

$V_{RRM}$  = Repetitive peak reverse voltage

$V_{RSM}$  = Non repetitive peak reverse voltage (2)

Repetitive peak reverse leakage current	$I_{RRM}$	10 mA 75 mA (3)
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### Notes:

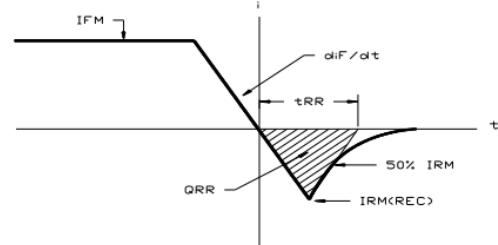
All ratings are specified for  $T_j=25^\circ\text{C}$ , unless otherwise stated

(1) All voltage ratings are specified for an applied 50Hz/60Hz sinusoidal waveform over the temperature range -40 to  $+125^\circ\text{C}$ .

(2) 10 msec. max. pulse width

(3) Maximum value for  $T_j = 125^\circ\text{C}$ .

(4) See parameter definition below :



REVERSE RECOVERY CHARACTERISTIC

### Conducting - on state

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Average forward current	$I_{F(AV)}$		925		A	Sinewave 180°, $T_c = 70^\circ\text{C}$
RMS forward current	$I_{FRMS}$		1450		A	Nominal value
Peak one cycle surge (non repetitive) current	$I_{FSM}$		13800		A	10 msec (50Hz), sinusoidal wave-shape, 180° conduction, $T_j = 125^\circ\text{C}$
$I^2t$	$I^2t$		$9.5 \times 10^5$		$\text{A}^2\text{s}$	8.3 msec and 10.0 msec
Peak forward voltage	$V_{FM}$		1.75		V	$I_{FM} = 1000\text{A}$ ; Duty cycle $\leq 0.01\%$ ; $T_j = 25^\circ\text{C}$
Reverse Recovery Current (4)	$I_{RM(REC)}$		45		A	$I_{FM} = 1000\text{A}$ ; $dI_F/dt = 10\text{ A}/\mu\text{s}$ ; $T_{j_{max}}$
Reverse Recovery Charge (4)	$Q_{rr}$	*	200	$\mu\text{C}$		$I_{FM} = 1000\text{A}$ ; $dI_F/dt = 25\text{ A/s}$ ; $T_{j_{max}}$
Reverse Recovery Time (4)	$t_{rr}$	*	*		$\mu\text{s}$	

\* For guaranteed maximum values, contact factory

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Operating temperature	$T_j$	-40	+125		°C	
Storage temperature	$T_{stg}$	-40	+140		°C	
Thermal resistance - junction to case	$R_\Theta(j-c)$		0.023 0.046		°C/W	Double sided cooled Single sided cooled
Thermal resistance - case to heatsink	$R_\Theta(c-s)$		0.010 0.020		°C/W	Double sided cooled * Single sided cooled*
Mounting force	P			25	kN	
Weight	W			0.46	kg.	

\* Mounting surfaces smooth, flat and greaseless

## CASE OUTLINE AND DIMENSIONS

